Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-7 **Mounting Method:** Terminal Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 60.0 repetitive peak reverse voltage **Capacitance Rating In Picofarads:** 10.0 Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: Unit Of Measure: **Demilitarization:** Fiig: A110a0

N/a

No